

# . reescale Semiconductor Technical Data

Document Number: MHW8205

Rev. 6, 3/2003

# **CATV Amplifier Module**

## **Features**

- Specified for 77-, 110- and 128-Channel Loading
- **Excellent Distortion Performance**
- Silicon Bipolar Transistor Technology
- · Unconditionally Stable Under All Load Conditions

## **Applications**

- CATV Systems Operating in the 40 to 860 MHz Frequency Range
- Output Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems

24 Vdc Supply, 40 to 860 MHz, CATV Forward Power Doubler Amplifier Module

# MHW8205

860 MHz **20.2 dB GAIN** 128-CHANNEL **CATV AMPLIFIER MODULE** 



## **Table 1. Maximum Ratings**

| Rating                           | Symbol           | Value       | Unit |
|----------------------------------|------------------|-------------|------|
| RF Voltage Input (Single Tone)   | V <sub>in</sub>  | +70         | dBmV |
| DC Supply Voltage                | V <sub>CC</sub>  | +28         | Vdc  |
| Operating Case Temperature Range | T <sub>C</sub>   | -20 to +100 | °C   |
| Storage Temperature Range        | T <sub>stg</sub> | -40 to +100 | °C   |

Table 2. Electrical Characteristics ( $V_{CC}$  = 24 Vdc,  $T_{C}$  = +30°C, 75  $\Omega$  system unless otherwise noted)

| Characteristic   | :   | Symbol  | Min         | Тур                  | Max                  | Unit         |
|--|---|---|-------------|----------------------|----------------------|--------------|
| Frequency Range  |   | BW  | 40          | _                    | 860                  | MHz          |
| Power Gain   | 50 MHz<br>860 MHz                                       | G <sub>p</sub>  | 19.3<br>20  | 19.8<br>20.2         | 20.3<br>21.5         | dB           |
| Slope  | 40 - 860 MHz  | S   | 0           | .4                   | 1.5                  | dB           |
| Gain Flatness (40 - 860 MHz, Peak to Va  | alley)  | G <sub>F</sub>  | _           | 0.3                  | 1.0                  | dB           |
| Return Loss — Input/Output (Z <sub>o</sub> = 75 Ohms)<br>@ 40 MHz<br>@ f > 40 MHz (Derate)                         |   | IRL/ORL   | 19<br>—     | _<br>_               | <br>0.006            | dB<br>dB/MHz |
| Composite Second Order (V <sub>out</sub> = +40 dBmV/ch., Worst Case) (V <sub>out</sub> = +44 dBmV/ch., Worst Case) | 128-Channel FLAT<br>110-Channel FLAT<br>77-Channel FLAT | CSO <sub>128</sub><br>CSO <sub>110</sub><br>CSO <sub>77</sub> | _<br>_<br>_ | - 69<br>- 70<br>- 80 | - 60<br>- 63<br>- 68 | dBc          |



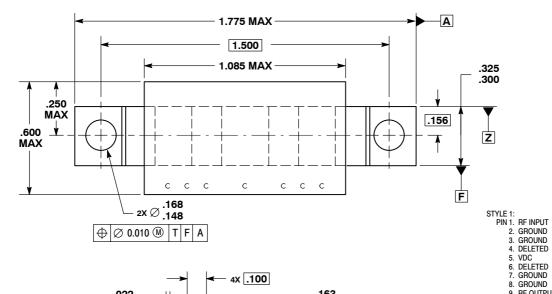
Table 2. Electrical Characteristics ( $V_{CC}$  = 24 Vdc,  $T_{C}$  = +30°C, 75  $\Omega$  system unless otherwise noted) (continued)

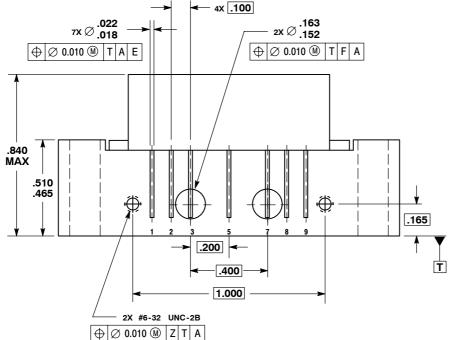
| Characteristic   |   | Symbol  | Min         | Тур                      | Max                  | Unit |
|--|---|---|-------------|--------------------------|----------------------|------|
| Cross Modulation Distortion @ Ch 2<br>(V <sub>out</sub> = +40 dBmV/ch., FM = 55 MHz)<br>(V <sub>out</sub> = +44 dBmV/ch., FM = 55 MHz) | 128-Channel FLAT<br>110-Channel FLAT<br>77-Channel FLAT | $\begin{array}{c} XMD_{128} \\ XMD_{110} \\ XMD_{77} \end{array}$ | _<br>_<br>_ | -72<br>-67<br>-71        | - 64<br>- 62<br>- 68 | dBc  |
| Composite Triple Beat<br>(V <sub>out</sub> = +40 dBmV/ch., Worst Case)<br>(V <sub>out</sub> = +44 dBmV/ch., Worst Case)                | 128-Channel FLAT<br>110-Channel FLAT<br>77-Channel FLAT | CTB <sub>128</sub><br>CTB <sub>110</sub><br>CTB <sub>77</sub>     | <br>_<br>_  | -66<br>-63<br>-71        | - 63<br>- 61<br>- 69 | dBc  |
| Noise Figure   | 50 MHz<br>550 MHz<br>750 MHz<br>860 MHz                 | NF  | <br><br>    | 5.0<br>5.8<br>6.2<br>7.0 | 6.0<br>—<br>—<br>8.0 | dB   |
| DC Current (V <sub>DC</sub> = 24 V, T <sub>C</sub> = 30°C)   |   | I <sub>DC</sub>   | 365         | 400                      | 435                  | mA   |

# ARCHIVE INFORMATION

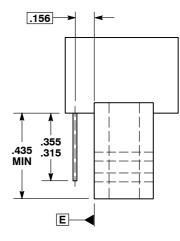


## **PACKAGE DIMENSIONS**





**CASE 714Y-04 ISSUE E** 



9. RF OUTPUT

- NOTES:
  1. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: INCH.

**ARCHIVE INFORMATION** 

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